

	<h2 style="color: red;">RFD16N05LSM9A</h2> <p><b>Hersteller-Teilenummer:</b> RFD16N05LSM9A</p> <hr/> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 50V 16A TO-252AA</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">RFD16N05LSM9A.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 42623 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	RFD16N05LSM9A
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 50V 16A TO-252AA
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	42623 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	60W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	16A (Tc)
Rds On (Max) @ Id, Vgs	47 mOhm @ 16A, 5V
VGS (th) (Max) @ Id	2V @ 250mA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	4V, 5V
Vgs (Max)	±10V
Verpackung	Tape & Reel (TR)






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Sie können auch interessiert sein:

 <p><b>RFD16N05LSM9A</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p><b>RFD16N05SM9A</b> Fairchild/ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p><b>RFD16N05SM9A</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p><b>RFD16N05LSM-NL VB</b> RFD16N05LSM-NL VB</p>
 <p><b>RFD16N05SM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p><b>RFD16N05LSM96S5000</b> Original RFD16N05LSM96S5000 Original</p>	 <p><b>RFD16N05LSM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p><b>RFD16N05SM</b> Fairchild/ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>

### heiße Teile

Mehr

 RFD15N06LESM	 RFD15P05	 RFD15P05	 RFD15P05SM	 RFD15P05SM
 RFD15P05SM9A	 RFD15P06	 RFD15P06LSM	 RFD15P06SM	 RFD15P06SM9AS2463
 RFD16N02	 RFD16N02L	 RFD16N02LSM	 RFD16N02LSM9A	 RFD16N03L
 RFD16N03LSM	 RFD16N03LSM9A	 RFD16N05	 RFD16N05	 RFD16N05L
 RFD16N05LSM	 RFD16N05LSM	 RFD16N05LSM-NL	 RFD16N05LSM96S5000	 RFD16N05LSM9A
 RFD16N05SM	 RFD16N05SM	 RFD16N05SM9A	 RFD16N05SM9A	 RFD16N06
 RFD16N06L	 RFD16N06LESM	 RFD16N06LESM9A	 RFD16N06LESM9A	 RFD16N06SM9A
 RFD20N03SM	 RFD20N03SM9A	 RFD3055L	 RFD3055LE	 RFD3055LE
 RFD3055LESM	 RFD3055LESM	 RFD3055LESM9A	 RFD3055LESM9A	 RFD3055LESM9AS2568
 RFD3055RLESM96	 RFD3055RLESM9A	 RFD3055SM	 RFD3055SM	 RFD3055SM9A

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